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RAL	DMATIONI	NICCI	OSHIDE	Application Number	10/796,442		
INFORMATION DISCLOSURE				Filing Date	March 9, 2004		
STATEMENT BY APPLICANT				First Named Inventor	Swihart et al.		
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				Examiner Name	To Be Assigned		
Sheet	1	of	4	Attorney Docket Number	19226/2282 (R-5782)		

	U.S. PATENT DOCUMENTS							
Examiner Initials	Cite No. <sup>1</sup>	U.S. Petern Document  Number - Kind Code <sup>2</sup> (If known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Cohumas, Lines, Where Relevant Passages or Relevant Figures Appear			
AICS	1	US-6,471,930	10/29/2002	Kambe et al.				
AKS	2	US-2002/0142218	10/03/2002	Reitz et al.				
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	FOREIGN PATENT DOCUMENTS							
Examiner Initials	Cite No.	Foreign Patent Document	Name of Patentee or Pages, Columns Publication Date Applicant of Cited Document Relevant Passa		Pages, Columns, Lines, Where Relevant Passages or Relevant	s, Where Relevant		
		Country Code <sup>3</sup> Number <sup>4</sup> (If known)	мм-ор-үүүү		Figures Appear	1*		
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		OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS	T <sup>3</sup>
Examiner Initials	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	
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Sylitute for form 1449B/PTO Complete if Known 10/796,442 Application Number INFORMATION DISCLOSURE March 9, 2004 Filing Date STATEMENT BY APPLICANT Swihart et al. First Named Inventor (use as many sheets as necessary) 2812 Group Art Unit To Be Assigned Examiner Name of 4 Attorney Docket Number 3 19226/2282 (R-5782) Sheet

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS					
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